

C2012X8R1H683M125AA

TDK Item Description : C2012X8R1H683MT****



Application & Main Feature

Commercial Grade (High Temperature Application)

Series

C2012 [EIA CC0805]



Dimensions

L 2.00mm +/-0.2mm
 W 1.25mm +/-0.2mm
 T 1.25mm +/-0.2mm
 B 0.20mm Min.
 G 0.50mm Min.

Temperature Characteristic

X8R (-55 to 150 degC +/-15%)

Rated Voltage

1H (50Vdc)

Capacitance

68nF

Capacitance Tolerance

M (+/-20%)

Dissipation Factor

3% Max.

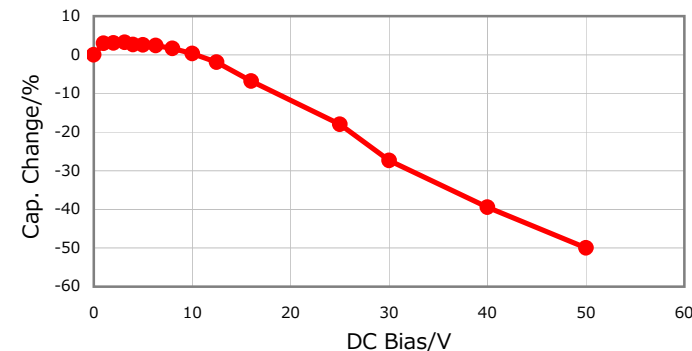
Insulation Resistance

7.35Gohm Min.

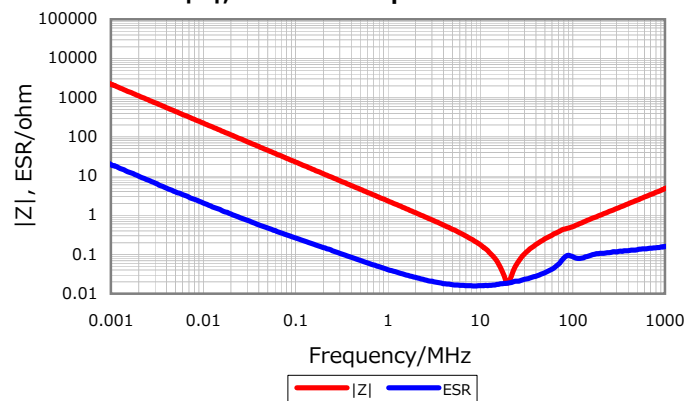
AEC-Q200

Not Applicable

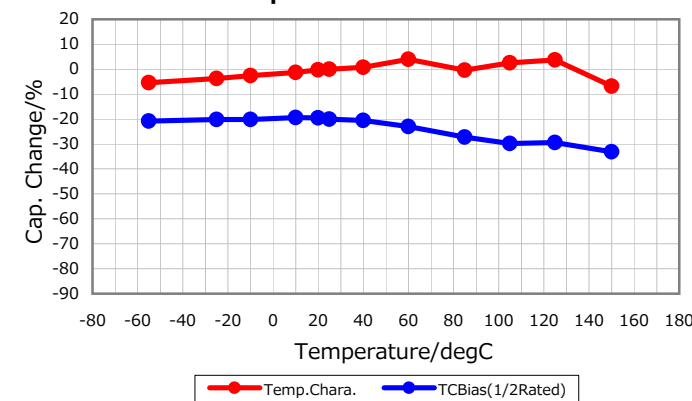
DC Bias Characteristic



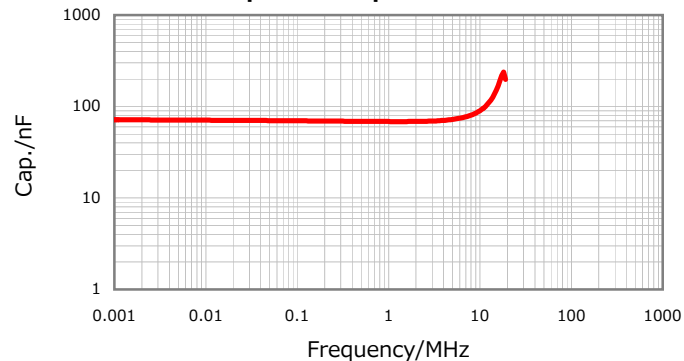
|Z|, ESR vs. Freq. Characteristics



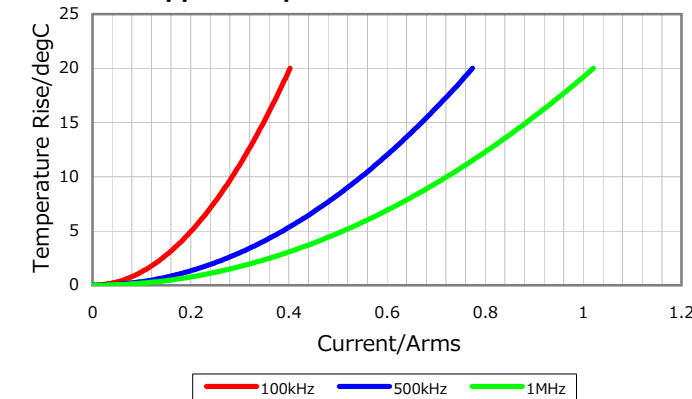
Temperature Characteristics



Cap. vs. Freq. Characteristic



Ripple Temperature Rise Characteristics



Characterization Sheet (Multilayer Ceramic Chip Capacitors)



All specifications are subject to change without notice.

January 3, 2016